NSN 5961-01-216-7269

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-216-7269 **Inclosure Material:** Glass **Overall Length:** 4.2 millimeters **Terminal Length:** 26.0 millimeters **Overall Diameter:** 2.0 millimeters Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.0 collector to emitter voltage, dc **Current Rating Per Characteristic:** 30.00 milliamperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No